

1. General description

Planar passivated SCR with sensitive gate in a SOT78 (TO-220AB) plastic package. This device is intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

2. Features and benefits

- Sensitive gate
- Planar passivated for voltage ruggedness and reliability
- Direct triggering from low power drivers and logic ICs

3. Applications

- General purpose switching
- Protection Circuits

4. Quick reference data

Table 1.	Quick	reference	data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		[1]	-	-	500	V
V _{RRM}	repetitive peak reverse voltage			-	-	500	V
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$; <u>Fig. 4</u> ; <u>Fig. 5</u>		-	-	35	A
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 113 °C; <u>Fig. 2;</u> <u>Fig. 3</u>		-	-	4	A
Static chara	acteristics				1		
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _i = 25 °C; <u>Fig. 7</u>		-	15	200	μA

[1] Although not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/µs.





5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	A - } − κ
2	А	anode		G sym037
3	G	gate		
mb	A	mounting base; connected to anode	TO-220AB (SOT78)	

6. Ordering information

Table 3. Ordering in	nformation					
Type number	Package	ackage				
	Name	Description	Version			
BT150-500R	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78			

7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

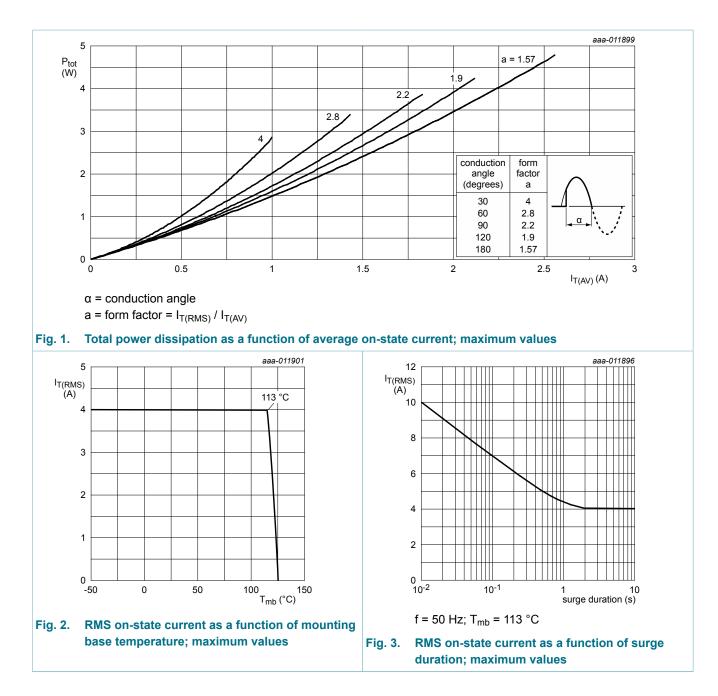
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		[1]	-	500	V
V _{RRM}	repetitive peak reverse voltage			-	500	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 113 °C; <u>Fig. 1</u>		-	2.5	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 113 °C; <u>Fig. 2;</u> <u>Fig. 3</u>		-	4	A
I _{TSM}	non-repetitive peak on-state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$; <u>Fig. 4</u> ; <u>Fig. 5</u>		-	35	A
		half sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 8.3 \text{ ms}$		-	38	А
l ² t	I ² t for fusing	t _p = 10 ms; SIN		-	6.1	A ² s
dI _T /dt	rate of rise of on-state current	I_T = 10 A; I_G = 50 mA; dI_G/dt = 50 mA/ µs		-	50	A/µs
I _{GM}	peak gate current			-	2	А
V _{RGM}	peak reverse gate voltage			-	5	V
P _{GM}	peak gate power			-	5	W
P _{G(AV)}	average gate power	over any 20 ms period		-	0.5	W
T _{stg}	storage temperature			-40	150	°C
Tj	junction temperature		[2]	-	125	°C

 Although not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/µs.

[2] Operation above 110°C may require the use of a gate to cathode resistor of $1k\Omega$ or less.

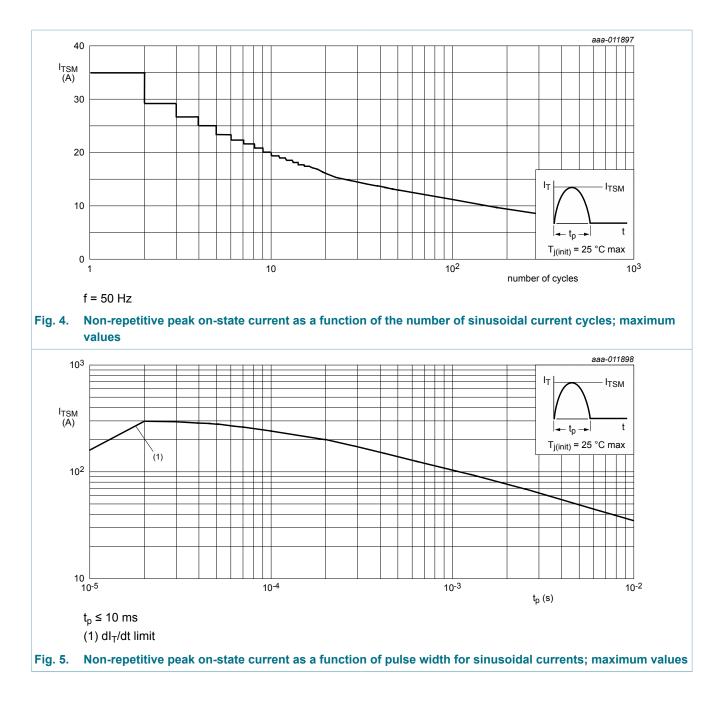
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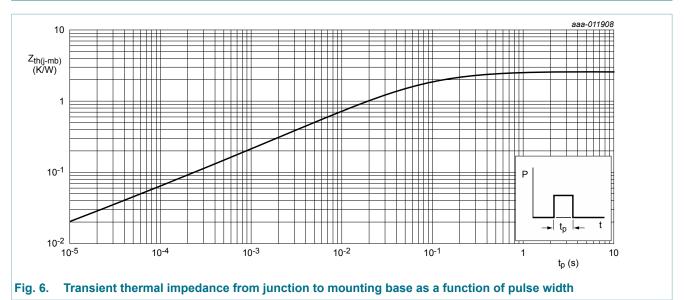
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8. Thermal characteristics

Table 5.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. <u>6</u>	-	-	2.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	60	-	K/W

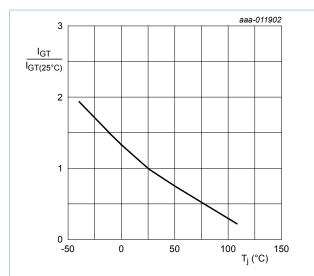


9. Characteristics

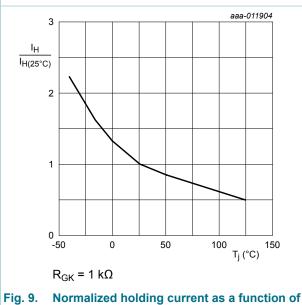
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	-	15	200	μA
IL	latching current	V _D = 12 V; I _G = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>	-	0.17	10	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	0.1	6	mA
V _T	on-state voltage	I _T = 5 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.23	1.8	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11	-	0.4	1	V
		V _D = 500 V; I _T = 0.1 A; T _j = 110 °C; Fig. 11	0.1	0.2	-	V
I _D	off-state current	V _D = 500 V; T _j = 125 °C	-	0.1	0.5	mA
I _R	reverse current	V _R = 500 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic cl	haracteristics	· · · · · · · · · · · · · · · · · · ·	I			
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 335 V; T _j = 125 °C; R _{GK} = 100 Ω; (V _{DM} = 67% of V _{DRM}); exponential waveform; Fig. 12	-	50	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 10 A; V _D = 500 V; I _G = 5 mA; dI _G / dt = 0.2 A/µs; T _j = 25 °C	-	2	-	μs
t _q	commutated turn-off time	$\begin{split} &V_{DM} = 335 \text{ V}; \text{T}_{\text{j}} = 125 ^{\circ}\text{C}; \text{I}_{TM} = 8 \text{ A}; \\ &V_{R} = 10 \text{ V}; (\text{dI}_{\text{T}}/\text{dt})_{\text{M}} = 10 \text{ A}/\text{\mu}\text{s}; \text{dV}_{\text{D}}/\\ &\text{dt} = 2 \text{ V}/\text{\mu}\text{s}; \text{R}_{\text{GK}} = 1 \text{k}\Omega; (\text{V}_{\text{DM}} = 67\% \text{ of } \\ &V_{\text{DRM}}) \end{split}$	-	100	-	μs

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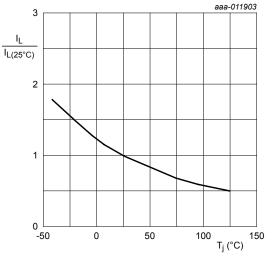
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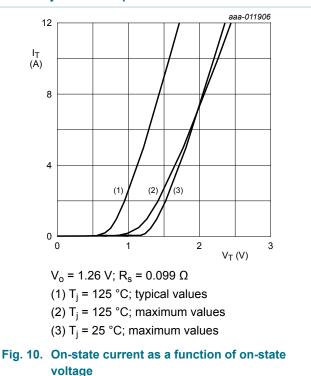


junction temperature



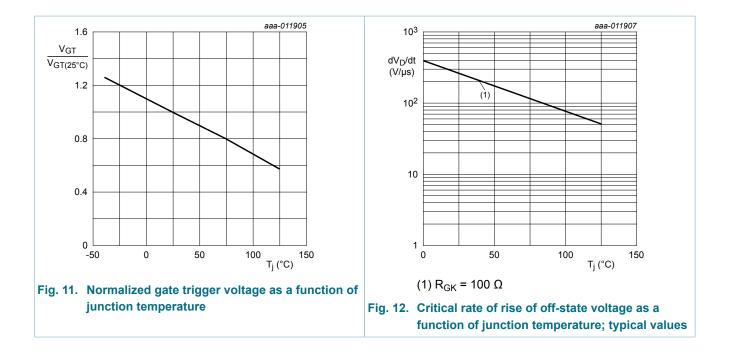






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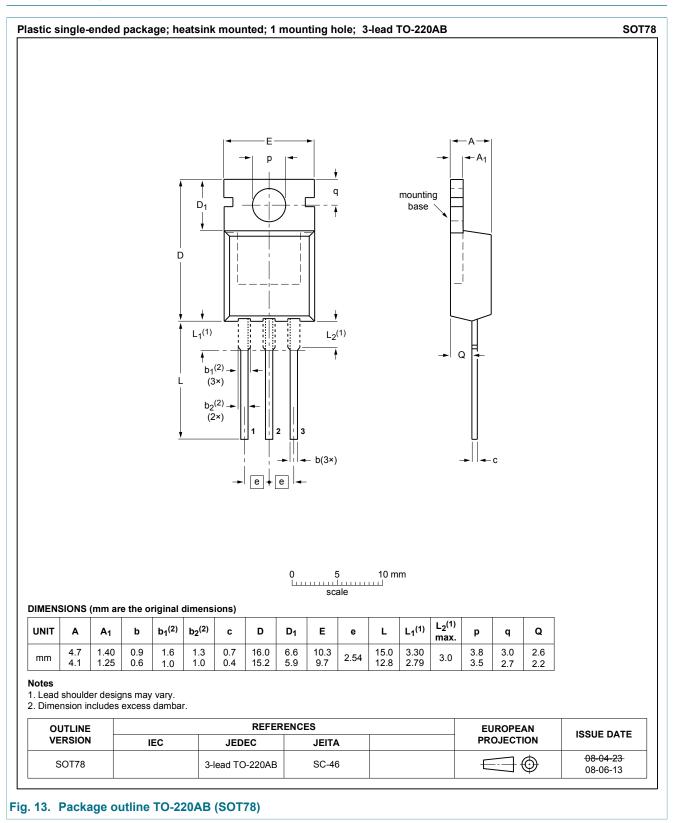
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10. Package outline



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11. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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